

ABSTRACT OF THE DISCLOSURE

A thin-film magnetic head includes a TMR element and a resistor element connected in parallel with the TMR element.

A resistance value R_{TMR} of the TMR element itself is $R_{\text{TMR}} \geq 240 \Omega$, a product RA of the resistance value of the TMR element itself and a cross-sectional area of the TMR element is $RA \geq 3 \Omega \cdot \mu\text{m}^2$, and a resistance value R_{PARA} of the resistor element is $R_{\text{PARA}} \leq 480 \Omega$.